ZASWA-2-50DRA+

 $DC^2 - 5000 MHz$

The Big Deal

- Wide bandwidth DC² to 5000 MHz
- High Isolation, 70 dB typ.
- Very fast switching, 20ns typ.
- Low video break thru 45 mV_{p-p} typ.



CASE STYLE: CY353

Product Overview

The ZASWA-2-50DRA+ is an excellent high isolation, solid state SPDT, absorptive RF switch. With its broad frequency range, fast switching time and excellent RF performance, the ZASWA-2-50DRA+ is an excellent replacement for the Mini-Circuits' legacy switch model ZASWA-2-50DR+. Refer app note <u>AN-80-021</u> for more details. The wide bandwidth, high isolation and fast switching characteristics makes this switch a versatile choice for several RF applications & systems.

Key Features

Feature	Advantages
Integrated TTL Driver	-Operates at +5V to -5V -Low control current allows compatibility with a variety of driver circuits -Fast 20 ns typ.Switching time
Excellent for a Variety of Applications From Bench to Integrated Systems	-High speed testers -Automated switching networks -Wireless Infrastructure -Military
Excellent RF Performance	-Wide bandwidth: DC ² to 5000 MHz -Good Insertion Loss: 2.5 dB Typ -Low video leakage, 45 mVp-p typ.

^{2.} All RF connections must be blocked or held at 0V DC. Low frequency is determined by value of Coupling capacitors at RF ports.

Notes

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SPDT RF Switch

$50Ω DC^{2}-5000 MHz$

Absorptive RF Switch with Internal Driver Dual Supply Voltage, +5V to -5V

Product Features

- Wide bandwidth, DC2 to 5000 MHz
- Good Insertion loss, 2.5 dB typ.
- Internal TTL driver
- Fast switching, Rise/fall time, 4 ns typ.
- Wide operating temperature, -20°C to +85°C

D. D. Mini-Circuits

Generic photo used for illustration purposes only

ZASWA-2-50DRA+

CASE STYLE: CY353

Connectors Model
SMA ZASWA-2-50DRA+

+RoHS Compliant

The +Suffix identifies RoHS Compliance. See our web site for RoHS Compliance methodologies and qualifications

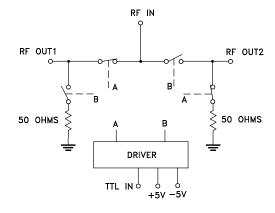
Typical Applications

- Cellular
- ISM, WCDMA, WIMAX
- PCN
- · Automated switching networks
- Military

General Description

The ZASWA-2-50DRA+ is a 50Ω absorptive, high isolation SPDT RF switch. It is designed for RF/wireless applications covering a broad frequency range from DC² to 5000 MHz with good insertion loss and Isolation. The ZASWA-2-50DRA+ operates with a dual supply voltage $\pm 5V$. This unit includes an internal driver circuitry which makes it easier to control switching with standard voltage levels.

Schematic and Application Circuit



2. All RF connections must be blocked or held at 0V DC. Low frequency is determined by value of Coupling capacitors at RF ports

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RF Electrical Specifications, DC² - 5000 MHz, T_{AMB}=25°C, Supply Voltage (+V, -V) =+5V, -5V

Parameter	Condition (MHz)	Min.	Тур.	Max.	Units	
Frequency Range		DC ²		5000	MHz	
	DC ² -100	_	1.3	2.0	dB	
	100-1000	_	1.7	2.5		
Insertion Loss	1000-2000	_	1.8	3.0		
	2000-5000	_	3.0	4.5		
	DC ² -100	68	90	_	dB	
Isolation between Common port and RF1/RF2 Ports	100-1000	75	90	_		
, , , , , , , , , , , , , , , , , , ,	1000-2000	65	82	_		
Return Loss (IN PORT)	2000-5000 DC ² -5000	40	65 14	_	dB	
Return Loss @ RF1/RF2 ports (ON STATE)	DC ² -5000		14.5		dВ	
			1	_		
Return Loss @ RF1/RF2 ports (OFF STATE)	DC ² -5000		16.5	_	dB	
	100-1000	_	>20	_		
Input 1dB Compression (1)	1000-2000	_	>20	_	dBm	
	2000-5000	_	>23	_		
DC	Electrical Specifications	S				
Supply Voltage (+V)		_	5	_	V	
Supply Voltage (-V)		_	-5	_	V	
Positive Supply Current	+V=5V	_	4.6	_	mA	
Negative Supply Current	-V=-5V	_	-8.2	_	mA	
Control Voltage Low		0	_	0.7	V	
Control Voltage High		2.1	_	5	V	
Control Current		_	_	2	mA	
S	witching Specifications					
Rise/Fall Time (10 to 90% or 90 to 10% RF)	+V=5V, -V=-5V	_	5	_	nSec	
Switching Time (50% CTRL to 90/10% RF)	+V=5V, -V=-5V	_	20	_	nSec	
Video Feed through (Control 0-5V, Frequency 1 MHz)	+V=5V, -V=-5V	_	45	_	mV _{P-P}	

^{1.} At low frequency(<100 MHz), the dynamic range of switch decreases.

Absolute Maximum Ratings

Parameter	Ratings		
Operating Temperature	-20°C to 85°C		
Storage Temperature	-55°C to 100°C		
Supply Voltage (+V & -V)	+5.5V, -5.5V		
Voltage Control	-0.2V min, +5.5V max		
RF input power ³	31 dBm		
ESD, HBM	Class 1A (250 to <500V) per JESD22-A114		

^{2.} All RF connections must be blocked or held at 0V DC. Low frequency is determined by value of Coupling capacitors at RF ports. 3 Frequency range of 500-5000 MHz.

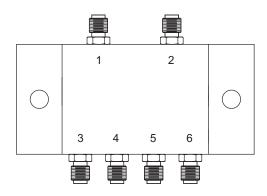
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Truth Table (State of control voltage selects the desired switch state)

Chata of Combrel Voltage	Switch State - RF IN to	
State of Control Voltage	RF1	RF2
Low	ON	OFF
High	OFF	ON
ON low insertion loss state		

ON- low insertion loss state OFF- Isolation State

Coaxial Configuration

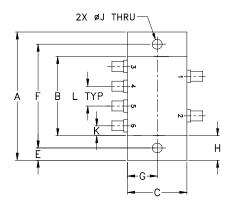


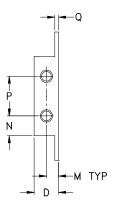
Coaxial Connections

Function	Port Number	Description	
RF IN	1	RF Common/ SUM Port	
RF1	3	RF Out #1/In Port #1	
RF2	6	RF Out #2/In Port #2	
Control	4	TTL Control IN	
+5V	2	Positive Supply Voltage	
-5V	5	Negative Supply Voltage	

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Outline Drawing (CY353)





		(inch)	ons (ensid	Dime	tline	Ou
Н	G	F	E	D	С	В	Α
.62	.75	2.620	.31	.62	1.50	2.00	3.24
15.75	19.05	66.55	7.87	15.75	38.10	50.80	82.30
wt	Q	Р	N	M	L	K	J
grams	.13	1.00	.50	.31	.50	.25	.250
65.0	3.30	25.40	12.70	7.87	12.70	6.35	6.35

Additional Detailed Technical Information

Additional information is available on our web site. To access this information enter the model number on our web site home page. Data Table **Performance Data** Swept Graphs S-Parameter (S2P Files) Data Set (.zip file) **Case Style** CY353 **Environmental Ratings ENV28T16**

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